

MOS INTEGRATED CIRCUIT μ PD16901

FLASH MEMORY VOLTAGE STEPUP DC/DC CONVERTER IC

The μ PD16901 is a DC/DC converter IC which produces a 12 V output from a 5 V input source. The integration of a control circuit and power MOSFET in the output stage on a single-chip allows a power supply for flash memory write and erasure to be configured with a reduced number of external components.

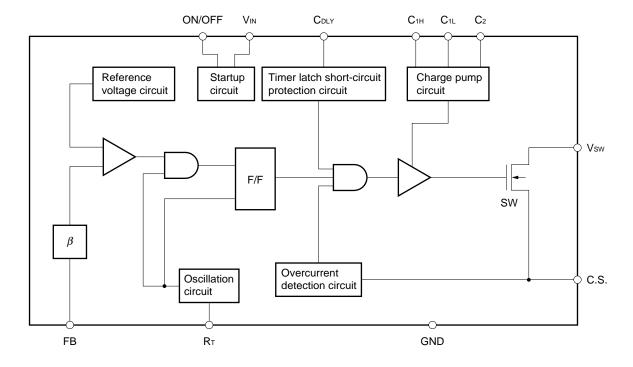
FEATURES

- · With an on-chip output stage power MOSFET, fewer external components are needed.
- The ALLMOS structure achieves low power consumption.
- · Internally set output voltage eliminates the need for adjustment.
- Output can be turned ON/OFF via an external signal.
- A timer latch type overcurrent protection circuit on chip

ORDERING INFORMATION

Part Number	Package
μPD16901GS	14-pin plastic SOP (300 mil)

BLOCK DIAGRAM



The information in this document is subject to change without notice.



ABSOLUTE MAXIMUM RATINGS (TA = 25 °C unless specified otherwise)

Item	Symbol	Condition	Rating	Unit
Supply voltage	Vin		7.0	V
Output voltage	Vsw		20	V
Total power dissipation	Рт	Note	0.9	W
Operating ambient temperature	TA		-20 to 85	°C
Storage temperature range	T _{stg}		-55 to +150	°C

Note When 90 mm \times 90 mm \times 1.6 mm thick glass epoxy board is mounted

RECOMMENDED OPERATING RANGE

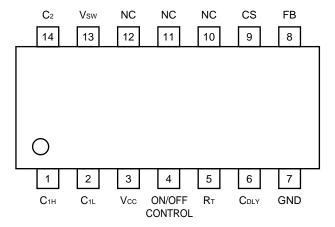
Item	Symbol	MIN.	TYP.	MAX.	Unit
Supply voltage	V _{DD}	4.5	5.0	5.5	V
Charge pump capacitor	C1, C2	0.033	0.1	0.47	μF
Operating ambient temperature	TA	0		70	°C

ELECTRICAL SPECIFICATIONS (TA = 25 °C, VIN = 5 V unless specified otherwise)

Item	Symbol	Condition	MIN.	TYP.	MAX.	Unit
(Oscillation block)						
Oscillation frequency	fosc	R _T = 68 kΩ	153	167	181	kHz
On duty	DUTY			67		%
(Low voltage misoperation preve	ntive circuit)					
Operation start voltage	VIN(start-up)		3.3	3.7	4.3	V
Operation stop voltage	VIN(stop)		2.7	3.2	3.8	V
Hysteresis width	VHYS		0.3	0.5	0.7	V
(Overcurrent detection block)						
Overcurrent detection voltage	VDET		270	300	330	mV
(On/off control block)						
ON/OFF pin input voltage	ViH	4.5 V ≤ V _{IN} ≤ 5.5 V	Vin*0.7			V
	VIL	4.5 V ≤ V _{IN} ≤ 5.5 V			VIN*0.3	V
ON/OFF pin input current	lı.	ON/OFF pin voltage = 0	-20	- 5	-1	μΑ
(Charge pump circuit)						
Output voltage	VснG	4.5 V ≤ V _{IN} ≤ 5.5 V 0 °C ≤ T _A ≤ 70 °C	8.0		11	V
(Short-circuit protection circuit)	·					
Timer latch pin output current	Iscp	R _T = 68 kΩ	2.0	3.3	4.5	μΑ
Timer latch detection voltage	VDETT		0.85	1.0	1.15	V
(Output block)	•	1				
Output stage on resistance	RDS(ON)	IPK = 0.5 A		0.3	0.5	Ω
Output stage leakage current	IDSOFF	Vps = 20 V			1.0	μΑ



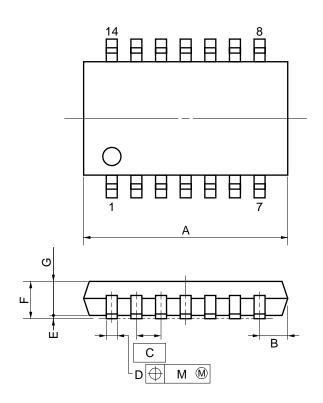
PIN CONFIGURATION (Top View)



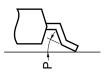


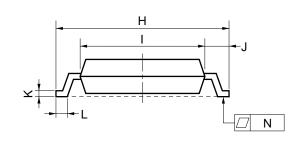
PACKAGE DRAWINGS

14 PIN PLASTIC SOP (300 mil)



detail of lead end





NOTE

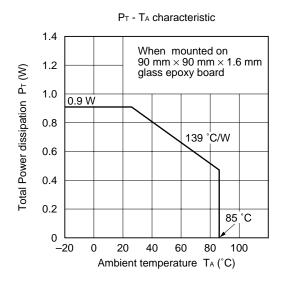
Each lead centerline is located within 0.12 mm (0.005 inch) of its true position (T.P.) at maximum material condition.

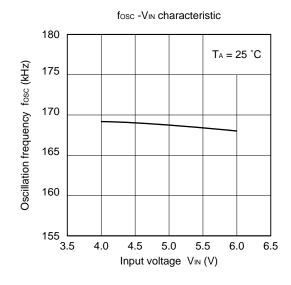
ITEM	MILLIMETERS	INCHES
Α	10.46 MAX.	0.412 MAX.
В	1.42 MAX.	0.056 MAX.
С	1.27 (T.P.)	0.050 (T.P.)
D	$0.40^{+0.10}_{-0.05}$	$0.016^{+0.004}_{-0.003}$
Е	0.1±0.1	0.004±0.004
F	1.8 MAX.	0.071 MAX.
G	1.55	0.061
Н	7.7±0.3	0.303±0.012
1	5.6	0.220
J	1.1	0.043
K	$0.20^{+0.10}_{-0.05}$	$0.008^{+0.004}_{-0.002}$
L	0.6±0.2	$0.024^{+0.008}_{-0.009}$
М	0.12	0.005
N	0.10	0.004
Р	3°+7° -3°	3°+7°

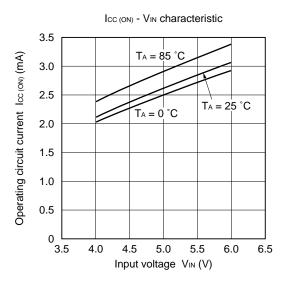
P14GM-50-300B-4

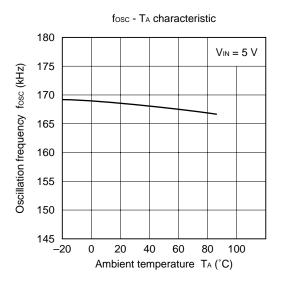


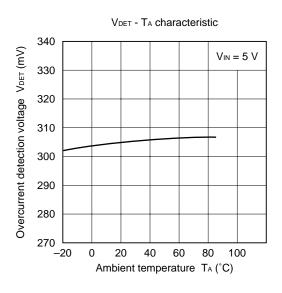
STANDARD CHARACTERISTIC CURVES

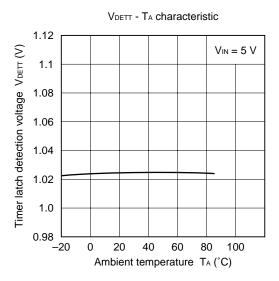


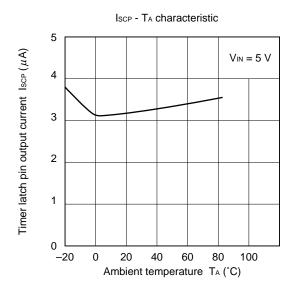


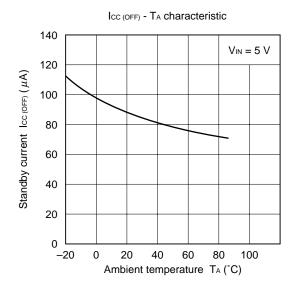






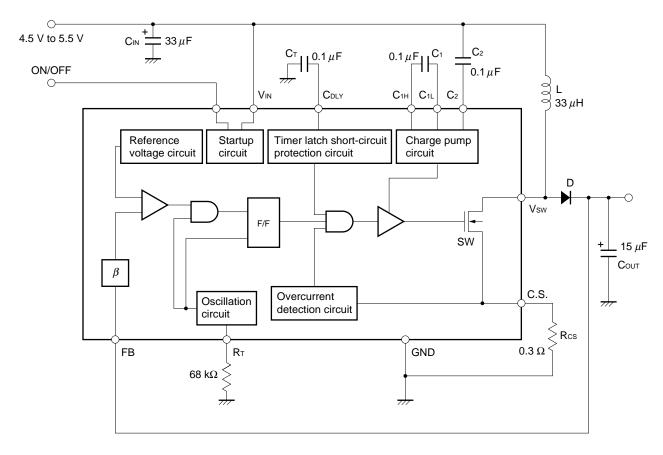








STANDARD CONNECTION DIAGRAM



Remark The circuit constants and circuit configuration in this connection diagram are shown for illustrative purposes and not intended for volume production design.

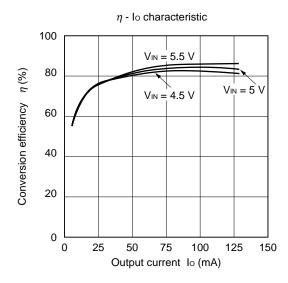
ELECTRICAL SPECIFICATIONS (as per standard connection diagram. $T_A = 25$ °C, $V_{IN} = 5$ V, $I_{OUT} = 140$ mA unless specified otherwise)

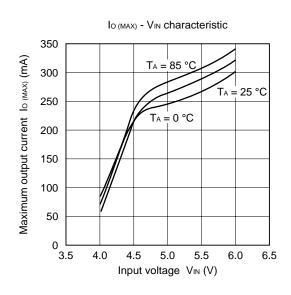
Item	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Output voltage	Vouт	$4.5 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V}$ $0 \text{ mA} \le \text{Io} \le 140 \text{ mA}$ $0 \text{ °C} \le \text{TA} \le 60 \text{ °C}$	11.52	12.00	12.48	٧
Input stability	REGIN	4.5 V ≤ V _{IN} < 5.5 V		0.5		%/V
Load stability	REG∟	0 mA ≤ lo < 140 mA		0.004		%/mA
Conversion efficiency	η			83		%
Operating circuit current	Icc	lo = 0			3.0	mA
Standby circuit current	Icc(off)	ON/OFF pin voltage = 0			100	μΑ
Startup voltage	VIN(start-up)			3.7	4.3	V

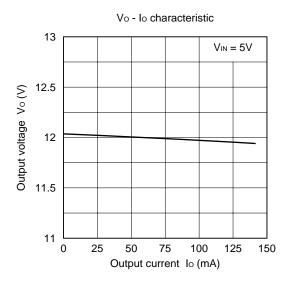
Remark These specifications are reference values confirmed with the standard connection diagram (without taking account of variations) and are not intended to guarantee the characteristics of the product as a DC/DC converter.

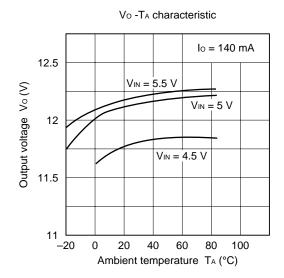


STANDARD CHARACTERISTIC CURVES (as per standard connection diagram)











RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the conditions recommended below.

For soldering methods and conditions other than those recommended, please contact your NEC sales representative.

For details of recommended soldering conditions, refer to the information document "Semiconductor Device Mounting Technology Manual."

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 235 °C; Duration: 30 sec. max. (210 °C or above): Number of times: Max. 3; Time limit: None ^{Note} Flux: Rosin type flux with reduced chlorine content (chlorine 0.2 Wt% or less) is recommended.	IR35-00-3
VPS	Package peak temperature: 215 °C; Duration: 40 sec. max. (200 °C or above): Number of times: 1; Time limit: None ^{Note} Flux: Rosin type flux with reduced chlorine content (chlorine 0.2 Wt% or less) is recommended.	VP15-00-1
Wave soldering	Package peak temperature: 260 °C or less, Duration: 10 sec. max., Preparatory heating temperature: 120 °C or less; Number of times: 1 Flux: Rosin type flux with reduced chlorine content (chlorine 0.2 Wt% or less) is recommended.	WS60-00-1

Note For the storage period after unpacking from the dry-pack, storage conditions are max. 25 °C, 65% RH.

Caution Use of more than one soldering method should be avoided.

REFERENCE DOCUMENTS

NEC Semiconductor Device Reliability/Quality Control System	10983E
Semiconductor Device Quality Guarantee Guide	MEI-1202
Semiconductor Device Mounting Technology Manual	C10535E

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Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.

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